## WEST

## Edit Saved Searches for User ogabor

Queries 329 through 378.

	Latest	Prov.	Next	Oldest		
Update	Cance	el Hel	p		Logout	
Delete: Delete ALL						

S#	Comment	Database	Query String	Delete?
S378		USPT	((((250/461.2)!.CCLS.))	U
S377		USPT	((((250/461.1)!.CCLS.)')	
S376		USPT	((((250/372)!.CCLS.))	
S375		USPT	((((250/201.3 )!.CCLS.) )	J
S374		USPT	((250/459.1)!.CCLS.)	
S373		USPT	((250/459.1)!.CCLS.) and fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	
S372		TDBD	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	
S371	·	DWPI	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	
S370		ЕРАВ	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	
S369	·	ЈРАВ	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	
S368		PGPB	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time and fit\$	J.

367	PGPB	fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time	
3366	USPT	(((250/\$)!.CCLS.)) and fluoresc\$ and molecule and intensity and (photon adj count) and distribution and time	
S365	USPT	((((250/\$)!.CCLS.)) and fluoresc\$ and molecule and intensity and (photon adj count) and distribution	
S364	USPT	(((250/458.1)!.CCLS.)) and fluoresc\$ and molecule and intensity and (photon adj count) and distribution	
S363	USPT	(((250/458.1)!.CCLS.)) and fluoresc\$ and molecule and intensity and (photon adj count)	
	USPT	((250/458.1)!.CCLS.)	
S362 S361	USPT	(integrated adj circuit) and passivation and conducting and photoresist and (electrical adj contacts) and layer and (barrier adj layer) and (first adj layer) and (second adj layer)	
S360 S360	USPT	(integrated adj circuit) and passivation and conducting and photoresist and (electrical adj contacts) and layer and (barrier adj layer)	
S359 S359	TDBD	(integrated adj circuit) and passivation and conducting and photoresist and (electrical adj contacts) and layer and (barrier adj layer) and indium	
S358	DWPI	(integrated adj circuit) and passivation and conducting and photoresist and (electrical adj contacts) and layer and (barrier adj layer) and indium	
S357	EPAB	(integrated adj circuit) and passivation and conducting and photoresist and (electrical adj contacts) and layer and (barrier adj layer) and indium	
S356	JPAB	(integrated adj circuit) and passivation an conducting and photoresist and (electrica adj contacts) and layer and (barrier adj layer) and indium	
		(integrated adj circuit) and passivation ar	nd